

## GR-10E003UG: E-mode GaN Power Transistor

### Description

GR-10E003UG is an enhancement mode GaN on Silicon power transistor. GR-10E003UG provides, high current and high operating speed which is suitable for DC to DC power supply applications.

### Key Specifications

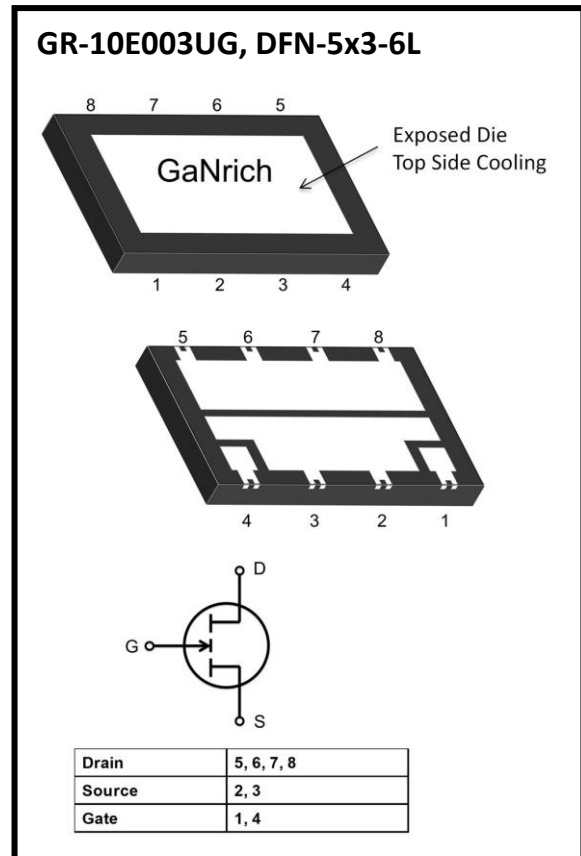
Part Number	GR-10E003UG
V <sub>DSS</sub> , min.	100V
I <sub>DS</sub> , Pulse (25°C, TPULSE = 300 μs)	150A
R <sub>DS(ON)</sub> , typ. @V <sub>gs</sub> =5V	3.1mΩ
Q <sub>G</sub> , typ.	15.5nC

### Features

- 100V enhancement mode power transistor
- High operating frequency
- R<sub>DS(on)</sub> = Typ. 3.1 mΩ
- Dual-side cooled package
- HS compliant

### Applications

- Switch Mode Power Supplies (SMPS)
- DC-DC Converters
- Fast Battery Charging
- Appliance Motor Drives



## 1. Electrical Characteristics

➤ **Table 1 Absolute maximum ratings**

Symbol	Parameter	Value	Unit
V <sub>DSS</sub>	Drain-source voltage	100	V
V <sub>(TR)DSS</sub>	Transient drain to source voltage <sup>a</sup>	120	V
V <sub>GSS</sub>	Gate- source voltage	-6V ~ +6V	V
I <sub>D</sub>	Drain current (continuous) at T <sub>C</sub> = 25°C operation	55	A
	Drain current (continuous) at T <sub>C</sub> = 100°C operation	37.9	A
I <sub>D,Pulse</sub>	Pulsed drain current (pulse width: 300μs, V <sub>gs</sub> =5V) <sup>b</sup>	150	A
T <sub>J</sub>	Operating temperature	-40 to +150	°C
T <sub>S</sub>	Storage temperature	-40 to +150	°C
MSL	Moisture sensitivity level	MSL3	

- a. In off-state, spike duty cycle D<0.01, spike duration <1μs
- b. Defined by product design and characterization. Value is not tested to full current in production

➤ **Table 2 Thermal Characteristics**

Symbol	Parameter	Value	Unit
R <sub>θJC_Top</sub>	Thermal resistance junction-case, Top	0.50	°C/W
R <sub>θJC_Bot</sub>	Thermal resistance junction-case, Bottom	0.50	°C/W
R <sub>θJA</sub>	Thermal resistance junction-ambient	60	°C/W

- a. Tested in package DFN 5x3.

➤ **Table 3 Electrical Characteristics** ( $T_{CASE} = 25\text{ }^{\circ}\text{C}$  unless otherwise stated)

Symbol	Parameter	Conditions	Values			Unit
			min.	typ.	max.	
$V_{DSS}$	Drain-source voltage	$V_{GS} = 0V, I_D = 150\mu A$	100	-	-	V
$V_{GS(th)}$	Gate threshold voltage	$V_{DS} = V_{GS}, I_D = 15mA$	0.8	1.7	2.3	V
$R_{DS(on)}$	Static drain-source on-resistance	$V_{GS} = 5V, I_D = 50A$	-	3.1	4.0	m $\Omega$
$I_{DSS}$	Drain-source leakage current	$V_{DS} = 80V, V_{GS} = 0V$	-	5.0	400	$\mu A$
$I_{GSS}$	Gate-to-Source Forward Leakage current	$V_{GS} = +5V$	-	0.08	16	mA
	Gate-to-Source Forward Leakage current	$V_{GS} = +5V, T_J = 125^{\circ}\text{C}$	-	0.75	22.5	mA
	Gate-to-Source Reverse Leakage current	$V_{GS} = -4V$	-	1.50	45.0	$\mu A$
$C_{ISS}$	Input capacitance	$V_{DS} = 50V, V_{GS} = 0V$	-	994	-	pF
$C_{OSS}$	Output capacitance		-	482	-	
$C_{RSS}$	Reverse transfer capacitance		-	55.5	-	
$Q_G$	Gate charge	$V_{DS} = 50V, V_{GS} = 5V, I_D = 50A$	-	15.5	-	nC
$Q_{GS}$	Gate-source charge	$V_{DS} = 50V, I_D = 50A$	-	5.8	-	
$Q_{GD}$	Gate-drain charge		-	2.6	-	
$Q_{OSS}$	Output charge	$V_{DS} = 50V, V_{GS} = 0V$	-	32.9	-	
$Q_{RR}$	Reverse recovery charge	-	-	0	-	

## 2- Typical Characteristic Curves

Fig 1. On-Region Characteristics

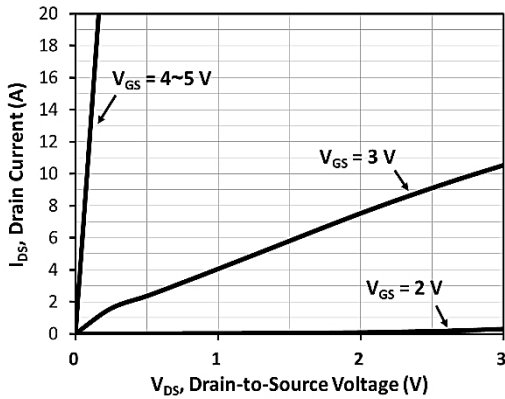


Fig 2. On-Resistance vs Drain Current and Temperature

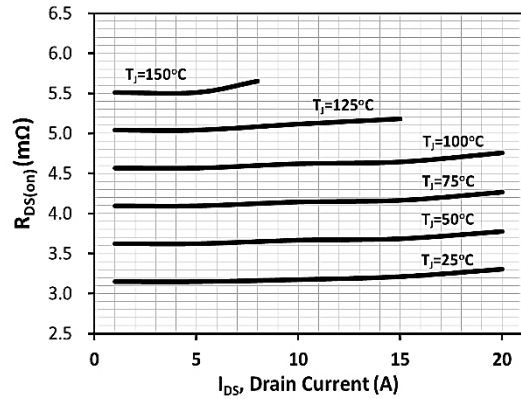


Fig 3. On-Resistance with Drain Current

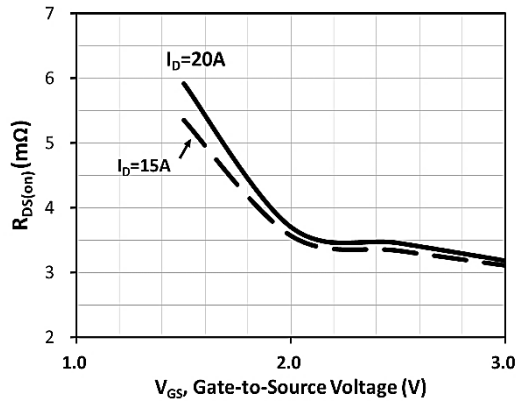


Fig 4. On-Resistance Variation with Temperature

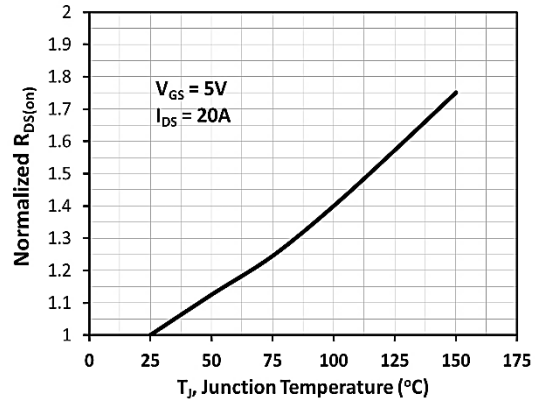


Fig 5. Threshold Voltage with Temperature

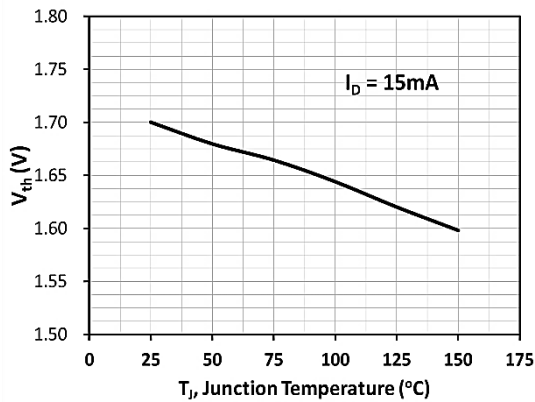
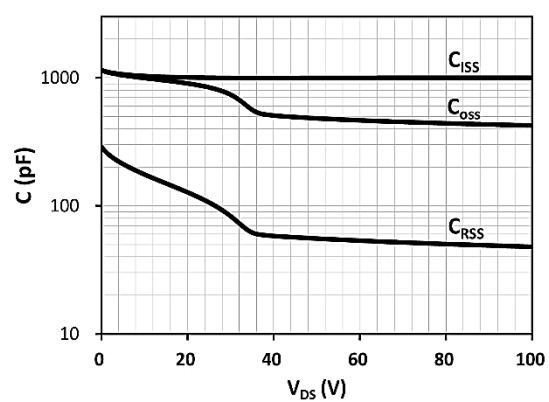


Fig 6. Capacitance Characteristics



**X**

Fig 7. Gate Charge Characteristics, Qg

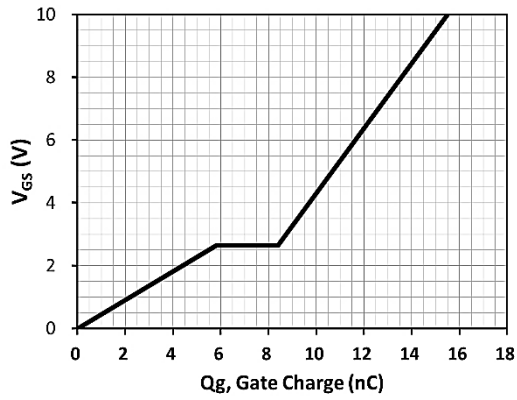
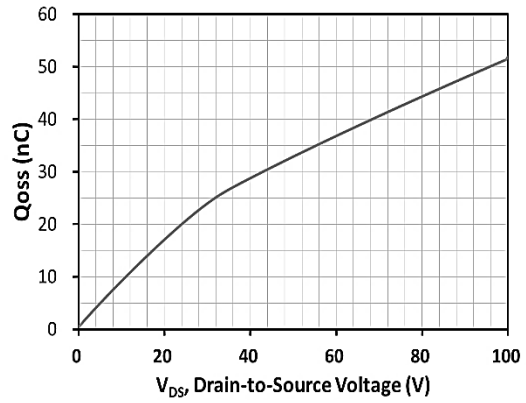
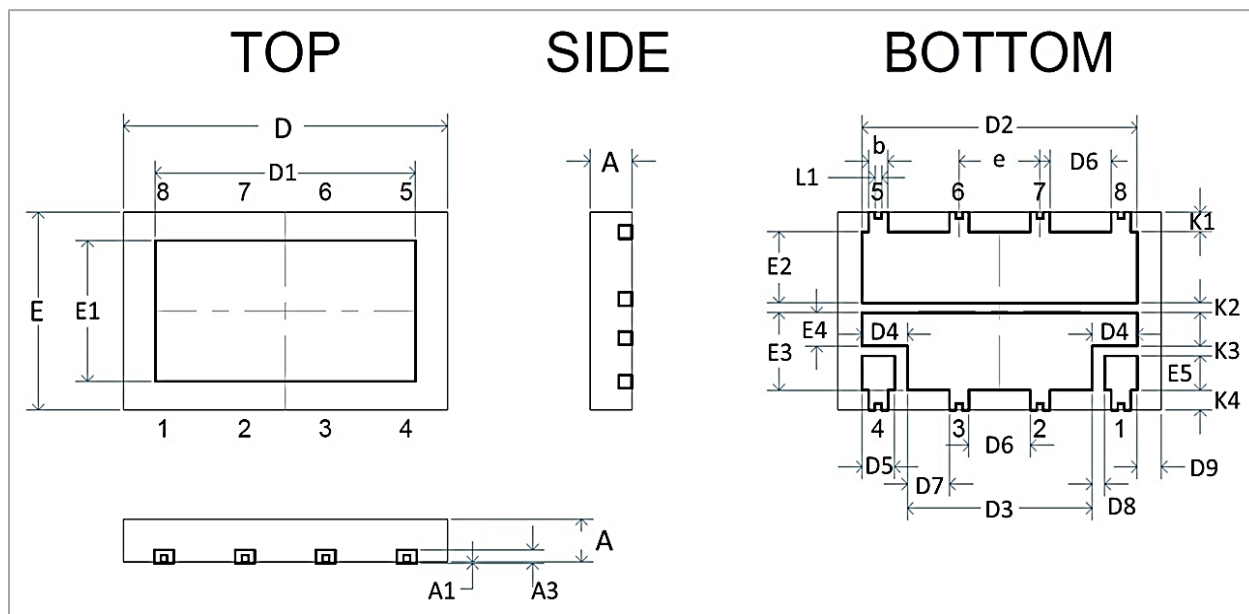


Fig 8. Capacitance Characteristics, Qoss



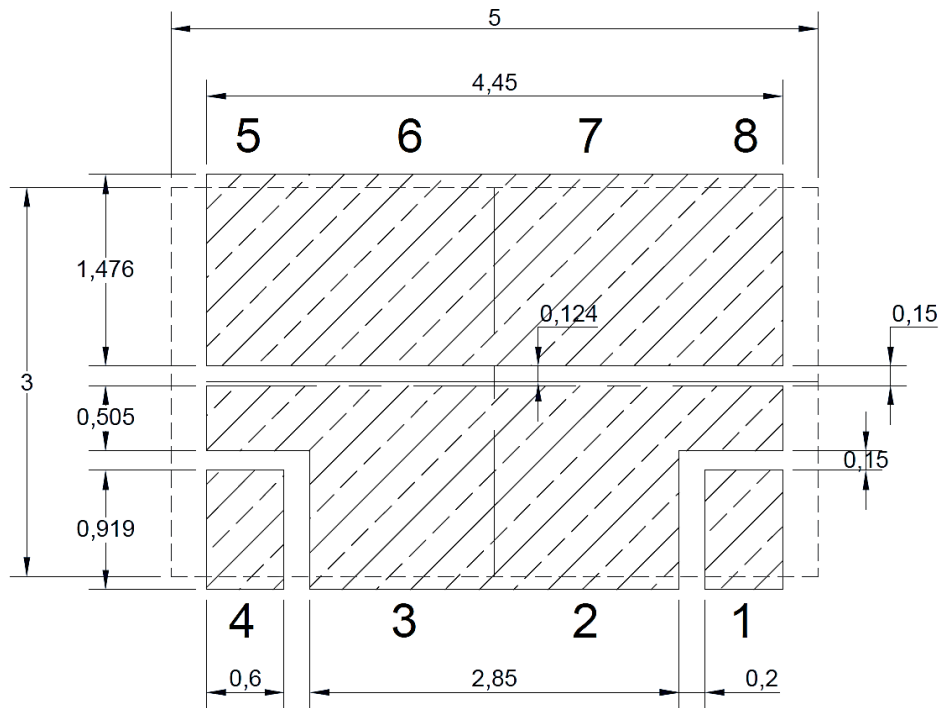
### 3. Package Outline Dimensions


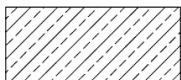


➤ **Table 4 Dimension of GR-DFN-5x3-6L**

SYMBOL	DIMENSION (MM)			SYMBOL	DIMENSION (IN MM)		
	MIN.	NOM.	MAX.		MIN.	NOM.	MAX.
<b>A</b>	0.60	0.65	0.70	<b>D7</b>	0.55	0.65	0.75
<b>A2</b>	--	0.02	0.05	<b>D8</b>	0.10	0.20	0.30
<b>A3</b>	0.203 REF			<b>D9</b>	0.365	0.375	0.385
<b>D</b>	4.90	5.00	5.10	<b>E1</b>	2.132 REF		
<b>E</b>	2.90	3.00	3.10	<b>E2</b>	0.976	1.076	1.176
<b>e</b>	1.25 BSC			<b>E3</b>	1.074	1.174	1.274
<b>b</b>	0.20	0.30	0.40	<b>E4</b>	0.405	0.505	0.605
<b>D1</b>	4.018 REF			<b>E5</b>	0.419	0.519	0.619
<b>D2</b>	4.15	4.25	4.35	<b>K1</b>	0.20	0.30	0.40
<b>D3</b>	2.75	2.85	2.95	<b>K2</b>	0.05	0.15	0.25
<b>D4</b>	0.60	0.70	0.80	<b>K3</b>	0.05	0.15	0.25
<b>D5</b>	0.40	0.50	0.60	<b>K4</b>	0.20	0.30	0.40
<b>D6</b>	0.85	0.95	1.05				

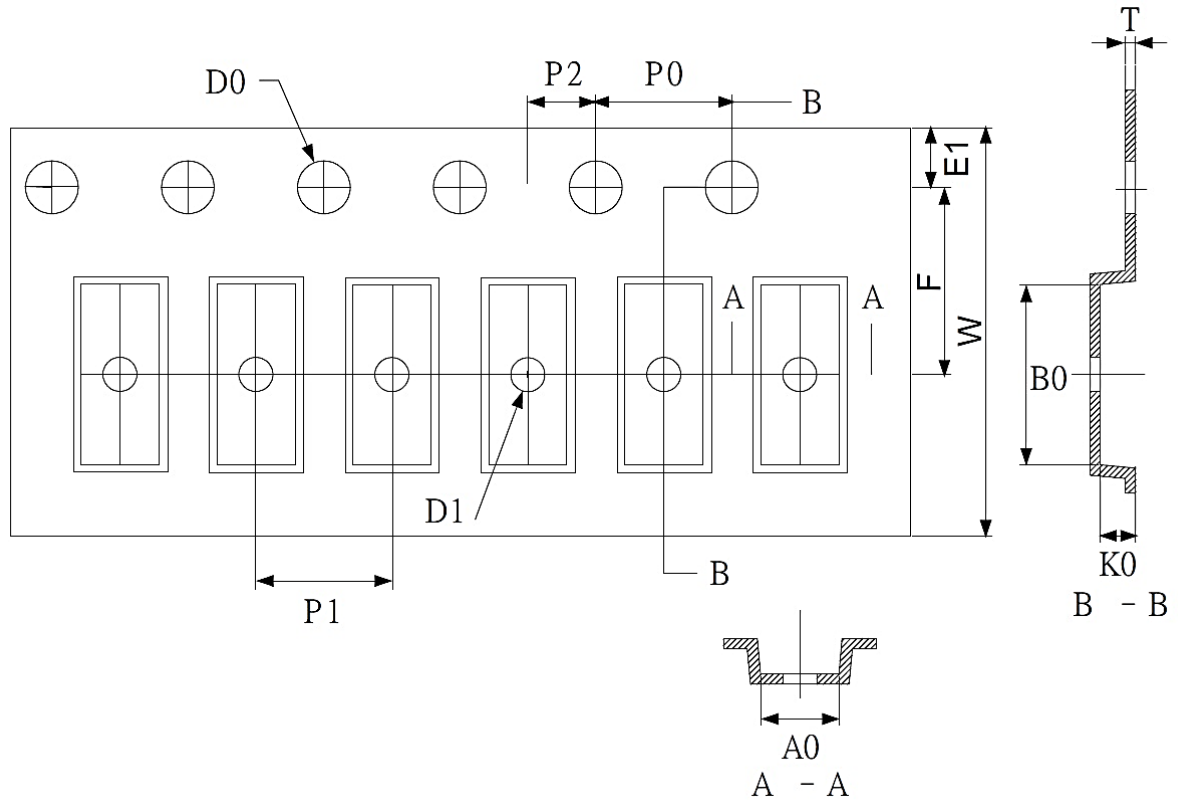
**Recommended PCB Soldering footprint**



-  Package outlines
-  PCB pad openings

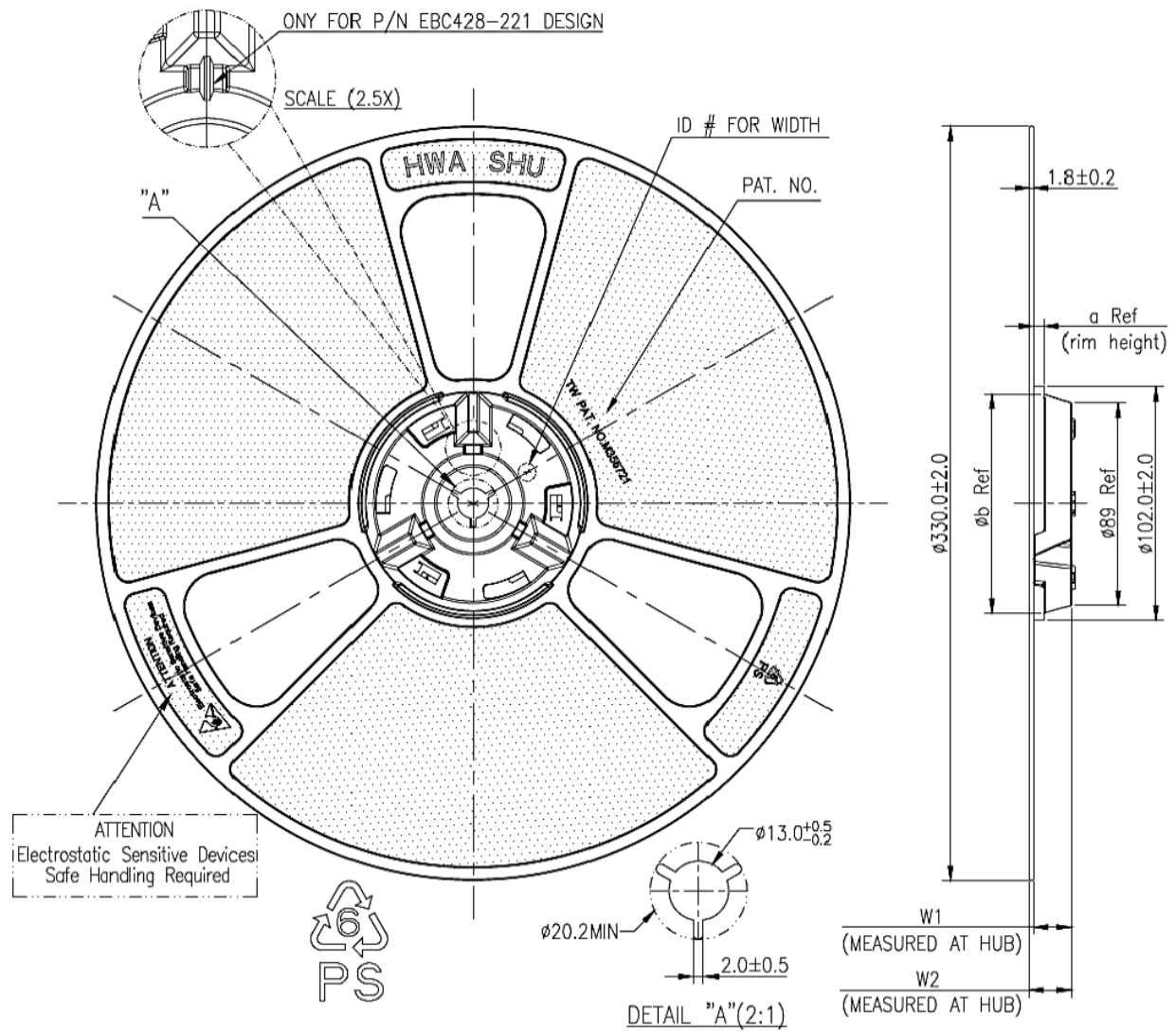
### 4. Tape and reel Information

13" Reel, Carrier Tape W=12mm



Application	A	H	T1	C	d	D	W	E1	F
<b>DFN 3x5_EP</b>	180 ± 0.1	50 min.	13.2 ± 0.2	13.0 ± 0.2	1.5 min.	21.0 ± 0.4	12.0 ± 0.3	1.75 ± 0.1	5.5 ± 0.1
	<b>P0</b>	<b>P1</b>	<b>P2</b>	<b>D0</b>	<b>D1</b>	<b>T</b>	<b>A0</b>	<b>B0</b>	<b>K0</b>
Unit: mm	4.0 ± 0.1	4.0 ± 0.1	2.0 ± 0.05	1.55 ± 0.1	1.0 ± 0.1	0.3 ± 0.05	2.3 ± 0.2	5.3 ± 0.2	1.0 ± 0.1

13" Reel, Carrier Tape W=12mm



## 5. Change Log

Version	Date	Description
0.1	Feb 05, 2025	Initial version
0.2	Sept 26, 2025	Electrical characteristics, Curve information revised.
0.3	Apr 16, 2026	Electrical characteristics revised.

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